

TQEHD3125V0

Ultra-low Capacitance Bidirectional Micro Packaged TVS Diodes for ESD Protection

Description

The TQEHD3125V0 is designed to protect voltage sensitive components from ESD and transient voltage events. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium.

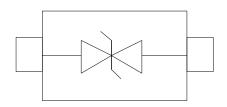
Applications

- Cellular phones
- Portable devices
- Digital cameras
- Power supplies

Features

- Small Body Outline Dimensions
- Low Body Height
- Peak Power up to 80 Watts @8x20_s Pulse
- Low Leakage current
- > Response Time is Typically < 1 ns
- IEC61000-4-2(ESD)±15kV(air),±8kV(contact)
- > IEC61000-4-2 Level 4 ESD Protection
- > IEC61000-4-4 Level 4 EFT Protection

• PIN configuration



SOD-523

ORDERING INF ORMATION

Device	Qty per	Marking	Reel
	Reel		Size
TQEHD3125V0	3000	LB	7Inch

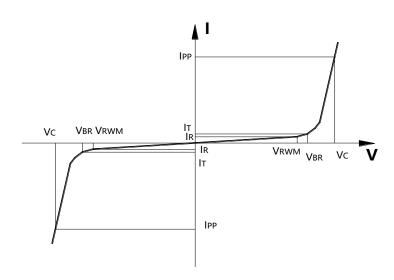
Parameter Peak Pulse Power (tp=8/20µs waveform) Peak Pulse Current(tp=8/20µs waveform)		Symbol	Value 35 2	Unit Watts A
		P _{PPP}		
		IPP		
ESD Rating per IEC61000-4-2:	Contact		8	10.7
	Air		15	KV
Lead Soldering Temperature		TL	260 (10 sec.)	°C



Operating Temperature Range	Тл	-55 ~ 150	°C
Storage Temperature Range	Тѕтс	-55 ~ 150	°C

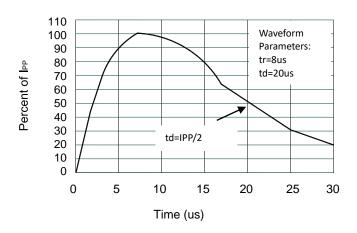
Electrical characteristics (Tamb=25°C Unless Otherwise Specified)					
Device V _{RWM} (V)	V	I _R @ V _{RWM}	V _{BR} @ 1 mA	Vc	С
	IR W VRWM	Min	@ lpp=2 A	Тур	
	(V)	(uA)	(Volts)	Type(V)	(pF)
TQEHD3125V0	5.0	1.0	6.0	14	3

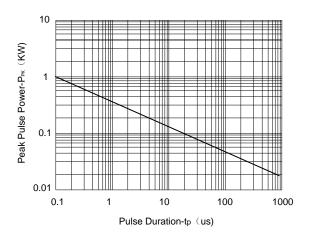
Symbol	Parameter	
VRWM	Working Peak Reverse Voltage	
V _{BR}	Breakdown Voltage @ IT	
Vc	Clamping Voltage @ IPP	
Ι _Τ	Test Current	
lгм	Leakage current at VRWM	
I PP	Peak pulse current	
Co	Off-state Capacitance	
С	Junction Capacitance	





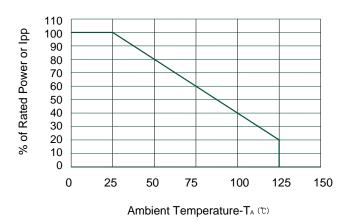
Typical electrical characterist applications





Pulse Waveform

Non-Repetitive Peak Pulse Power vs. Pulse Time



Power Derating Curve

Application Note

Electrostatic discharge (ESD) is a major cause of failure in electronic systems. Transient Voltage Suppressors (TVS) are an ideal choice for ESD protection. They are capable of clamping the incoming transient to a low enough level such that damage to the protected semiconductor is prevented.

Surface mount TVS offers the best choice for minimal lead inductance. They serve as parallel protection elements, connected between the signal lines to ground. As the transient rises above the operating voltage of the device, the TVS becomes a low impedance path diverting the transient current to ground. The TQEHD3125V0 is the ideal board evel protection of ESD sensitive semiconductor components.

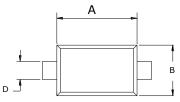
The tiny SOD-523 package allows design flexibility in the design of high density boards where the space saving is at a premium. This enables to shorten the routing and contributes to hardening against ESD.

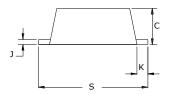


Mechanical Data

Case:SOD-523

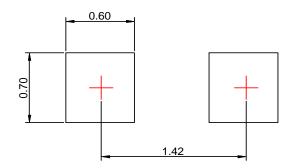
Case Material: Molded Plastic. UL Flammability





Dim∂	Millimeters₽		
Dilli	Min₽	Max₽	
A 43	1.10₽	1.30₽	
B 43	0.75₽	0.85₽	
C ₽	0.50₽	0.70₽	
D 43	0.25₽	0.35₽	
J₽	0.08₽	0.15₽	
K₽	0.15₽	0.25₽	
S₽	1.50₽	1.70₽	

Recommended Pad outline



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